

PMN52XP 20 V, P-channel Trench MOSFET 29 January 2016

**Product data sheet** 

### 1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in a small SOT457 (SC-74) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

### 2. Features and benefits

- Trench MOSFET technology
- Low threshold voltage
- Enhanced power dissipation capability of 1240 mW

### 3. Applications

- Relay driver
- High-speed line driver
- High-side loadswitch
- Switching circuits

### 4. Quick reference data

| Table 1. Qui           | ck reference data                |  |     |     |     |      |      |
|------------------------|----------------------------------|--|-----|-----|-----|------|------|
| Symbol                 | Parameter                        | Conditions   |     | Min | Тур | Max  | Unit |
| V <sub>DS</sub>        | drain-source voltage             | T <sub>j</sub> = 25 °C   |     | -   | -   | -20  | V    |
| V <sub>GS</sub>        | gate-source voltage              | -  |     | -12 | -   | 12   | V    |
| I <sub>D</sub>         | drain current                    | $V_{GS}$ = -4.5 V; $T_{amb}$ = 25 °C; t ≤ 5 s                      | [1] | -   | -   | -4.7 | А    |
| Static characteristics |                                  |  |     |     |     |      |      |
| R <sub>DSon</sub>      | drain-source on-state resistance | $V_{GS}$ = -4.5 V; I <sub>D</sub> = -3.7 A; T <sub>j</sub> = 25 °C |     | -   | 50  | 62   | mΩ   |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.



# 5. Pinning information

| Table 2. | Pinning | information |                    |                |
|----------|---------|-------------|--------------------|----------------|
| Pin      | Symbol  | Description | Simplified outline | Graphic symbol |
| 1        | D       | drain       | 6 5 4              | D              |
| 2        | D       | drain       |                    |                |
| 3        | G       | gate        |                    | G              |
| 4        | S       | source      | TSOP6 (SOT457)     | S<br>017aaa257 |
| 5        | D       | drain       | -                  |                |
| 6        | D       | drain       |                    |                |

# 6. Ordering information

| Table 3. Ordering information |         |  |         |  |  |  |
|-------------------------------|---------|--|---------|--|--|--|
| Type number                   | Package |  |         |  |  |  |
|                               | Name    | Description                                      | Version |  |  |  |
| PMN52XP                       | TSOP6   | plastic surface-mounted package (TSOP6); 6 leads | SOT457  |  |  |  |

# 7. Marking

| Table 4. Marking codes |              |
|------------------------|--------------|
| Type number            | Marking code |
| PMN52XP                | H3           |

### 8. Limiting values

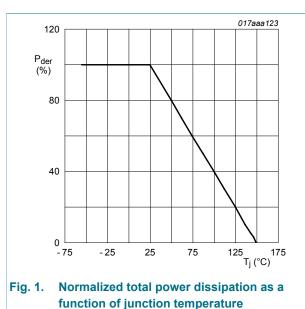
#### Table 5.Limiting values

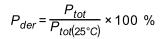
In accordance with the Absolute Maximum Rating System (IEC 60134).

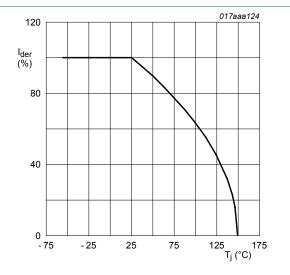
| Symbol           | Parameter               | Conditions  |     | Min | Мах  | Unit |  |  |
|------------------|-------------------------|---|-----|-----|------|------|--|--|
| V <sub>DS</sub>  | drain-source voltage    | T <sub>j</sub> = 25 °C                                |     | -   | -20  | V    |  |  |
| V <sub>GS</sub>  | gate-source voltage     |   |     | -12 | 12   | V    |  |  |
| I <sub>D</sub>   | drain current           | $V_{GS}$ = -4.5 V; $T_{amb}$ = 25 °C; t ≤ 5 s         | [1] | -   | -4.7 | А    |  |  |
|                  |                         | V <sub>GS</sub> = -4.5 V; T <sub>amb</sub> = 25 °C    | [1] | -   | -3.7 | А    |  |  |
|                  |                         | V <sub>GS</sub> = -4.5 V; T <sub>amb</sub> = 100 °C   | [1] | -   | -2.3 | А    |  |  |
| I <sub>DM</sub>  | peak drain current      | $T_{amb}$ = 25 °C; single pulse; $t_p \le 10 \ \mu s$ |     | -   | -15  | А    |  |  |
| P <sub>tot</sub> | total power dissipation | T <sub>amb</sub> = 25 °C                              | [2] | -   | 530  | mW   |  |  |
|                  |                         |   | [1] | -   | 1.24 | W    |  |  |
|                  |                         | T <sub>sp</sub> = 25 °C                               |     | -   | 4.46 | W    |  |  |
| Tj               | junction temperature    |   |     | -55 | 150  | °C   |  |  |
| T <sub>amb</sub> | ambient temperature     |   |     | -55 | 150  | °C   |  |  |
| T <sub>stg</sub> | storage temperature     |   |     | -65 | 150  | °C   |  |  |
| Source-dra       | Source-drain diode      |   |     |     |      |      |  |  |
| I <sub>S</sub>   | source current          | T <sub>amb</sub> = 25 °C                              | [1] | -   | -1.2 | А    |  |  |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.









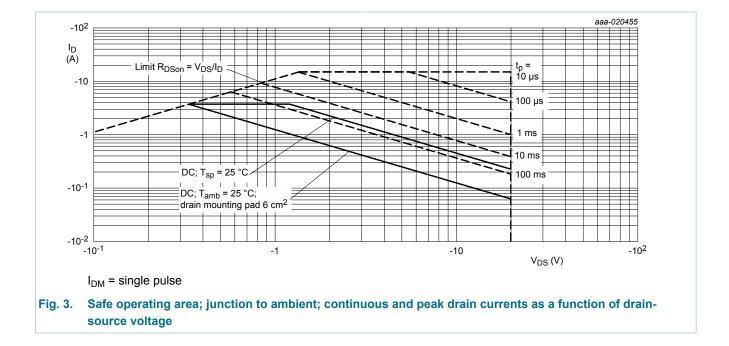
$$I_{der} = \frac{I_D}{I_{D(25^{\circ}C)}} \times 100 \%$$

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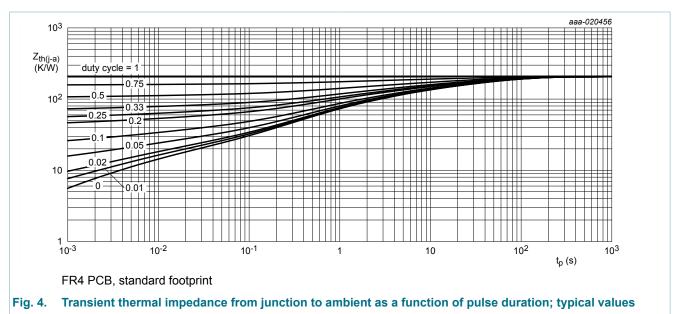


#### **Thermal characteristics** 9.

| Table 6. Thermal characteristics |  |                          |     |     |     |     |      |
|----------------------------------|--|--------------------------|-----|-----|-----|-----|------|
| Symbol                           | Parameter  | Conditions               |     | Min | Тур | Мах | Unit |
| from j                           | thermal resistance                                     | in free air              | [1] | -   | 205 | 235 | K/W  |
|                                  | from junction to ambient                               |                          | [2] | -   | 88  | 101 | K/W  |
|                                  | ambient  | in free air; $t \le 5 s$ | [2] | -   | 55  | 63  | K/W  |
| R <sub>th(j-sp)</sub>            | thermal resistance<br>from junction to solder<br>point |                          |     | -   | 24  | 28  | K/W  |

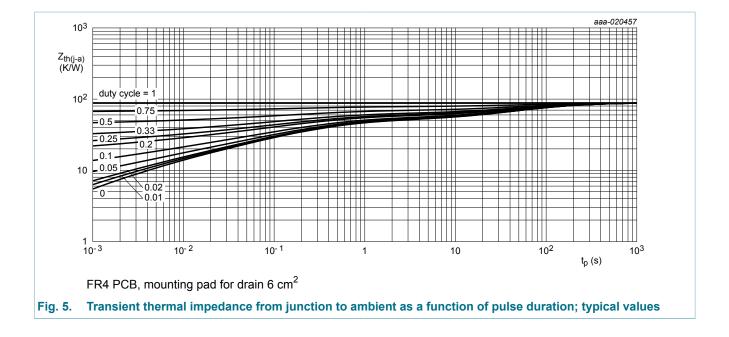
Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint. [1] [2]

Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.



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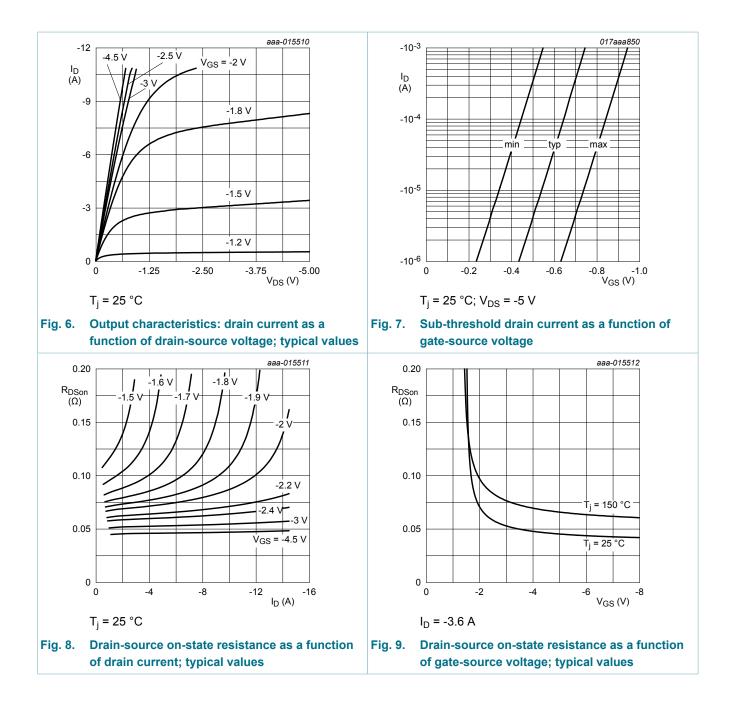


# **10. Characteristics**

| Symbol               | Parameter   | Conditions   | Min   | Тур   | Max  | Unit |
|----------------------|---|--|-------|-------|------|------|
| Static chara         |   |  |       |       |      |      |
| V <sub>(BR)DSS</sub> | drain-source<br>breakdown voltage   | $I_D$ = -250 µA; $V_{GS}$ = 0 V; $T_j$ = 25 °C                             | -20   | -     | -    | V    |
| V <sub>GSth</sub>    | gate-source threshold voltage   | $I_D$ = -250 µA; $V_{DS}$ = $V_{GS}$ ; $T_j$ = 25 °C                       | -0.47 | -0.65 | -0.9 | V    |
| I <sub>DSS</sub>     | drain leakage current   | $V_{DS}$ = -20 V; $V_{GS}$ = 0 V; $T_j$ = 25 °C                            | -     | -     | -1   | μA   |
| I <sub>GSS</sub>     | gate leakage current  | $V_{GS}$ = 12 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C                             | -     | -     | 100  | nA   |
|                      |   | $V_{GS}$ = -12 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C                            | -     | -     | -100 | nA   |
| R <sub>DSon</sub>    | drain-source on-state   | $V_{GS}$ = -4.5 V; I <sub>D</sub> = -3.7 A; T <sub>j</sub> = 25 °C         | -     | 50    | 62   | mΩ   |
| resistance           | resistance  | V <sub>GS</sub> = -4.5 V; I <sub>D</sub> = -3.7 A; T <sub>j</sub> = 150 °C | -     | 73    | 91   | mΩ   |
|                      |   | $V_{GS}$ = -2.5 V; I <sub>D</sub> = -3.2 A; T <sub>j</sub> = 25 °C         | -     | 64    | 84   | mΩ   |
|                      |   | V <sub>GS</sub> = -1.8 V; I <sub>D</sub> = -1 A; T <sub>j</sub> = 25 °C    | -     | 88    | 125  | mΩ   |
|                      | V <sub>GS</sub> = -1.5 V; I <sub>D</sub> = -0.1 A; T <sub>j</sub> = 25 °C | -  | 120   | 255   | mΩ   |      |
| 9 <sub>fs</sub>      | forward<br>transconductance   | $V_{DS}$ = -10 V; I <sub>D</sub> = -2 A; T <sub>j</sub> = 25 °C            | -     | 9     | -    | S    |
| Dynamic ch           | aracteristics   | · · · · ·  |       |       |      |      |
| Q <sub>G(tot)</sub>  | total gate charge   | $V_{DS}$ = -10 V; I <sub>D</sub> = -3.7 A; V <sub>GS</sub> = -4.5 V;       | -     | 8.5   | 12   | nC   |
| Q <sub>GS</sub>      | gate-source charge  | T <sub>j</sub> = 25 °C   | -     | 1.1   | -    | nC   |
| Q <sub>GD</sub>      | gate-drain charge   |  | -     | 2.1   | -    | nC   |
| C <sub>iss</sub>     | input capacitance   | $V_{DS}$ = -10 V; f = 1 MHz; $V_{GS}$ = 0 V;                               | -     | 763   | -    | pF   |
| C <sub>oss</sub>     | output capacitance  | T <sub>j</sub> = 25 °C   | -     | 68    | -    | pF   |
| C <sub>rss</sub>     | reverse transfer capacitance  |  | -     | 58    | -    | pF   |
| t <sub>d(on)</sub>   | turn-on delay time  | $V_{DS}$ = -10 V; I <sub>D</sub> = -3.7 A; V <sub>GS</sub> = -4.5 V;       | -     | 5.1   | -    | ns   |
| t <sub>r</sub>       | rise time   | $R_{G(ext)} = 6 \Omega; T_j = 25 °C$                                       | -     | 4.3   | -    | ns   |
| t <sub>d(off)</sub>  | turn-off delay time   | 1  | -     | 141   | -    | ns   |
| t <sub>f</sub>       | fall time   | 1  | -     | 62    | -    | ns   |
| Source-drai          | in diode  |  | I     |       | 1    |      |
| V <sub>SD</sub>      | source-drain voltage  | I <sub>S</sub> = -1.2 A; V <sub>GS</sub> = 0 V; T <sub>i</sub> = 25 °C     | -     | -0.8  | -1.2 | V    |

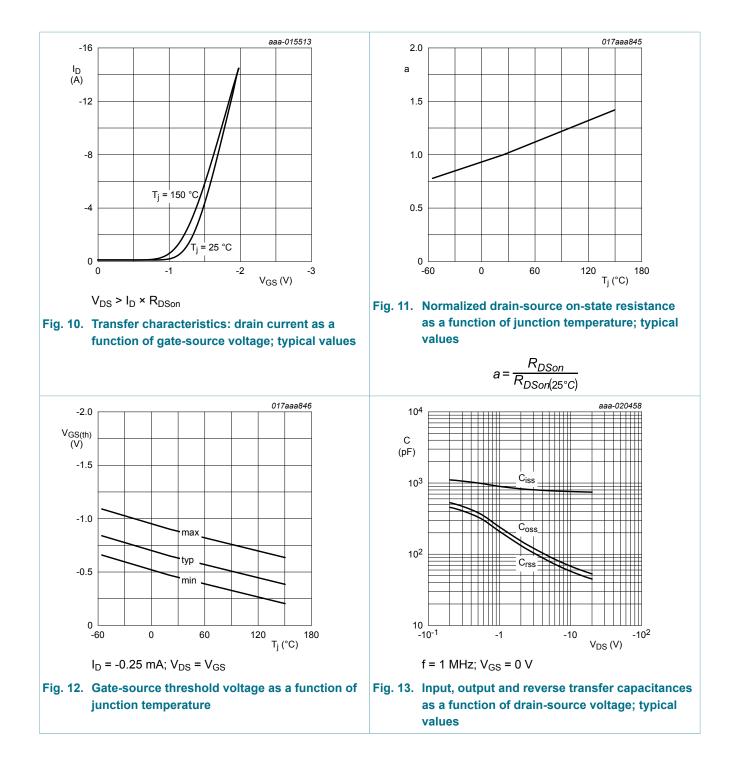
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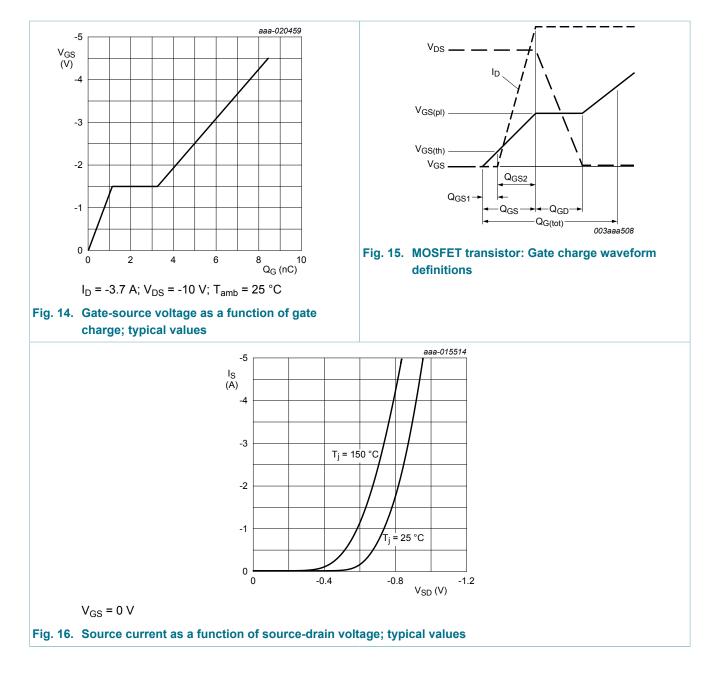
#### 20 V, P-channel Trench MOSFET



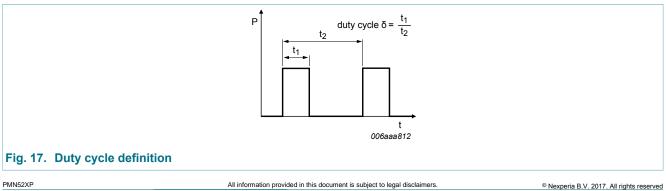
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# PMN52XP

#### 20 V, P-channel Trench MOSFET

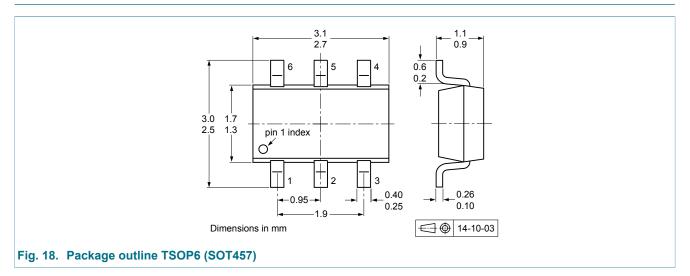


# **11. Test information**

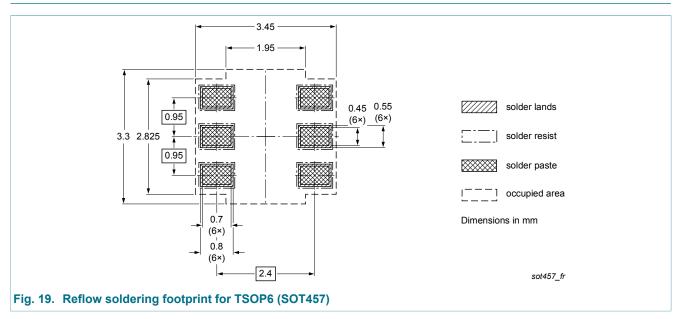


20 V, P-channel Trench MOSFET

### 12. Package outline

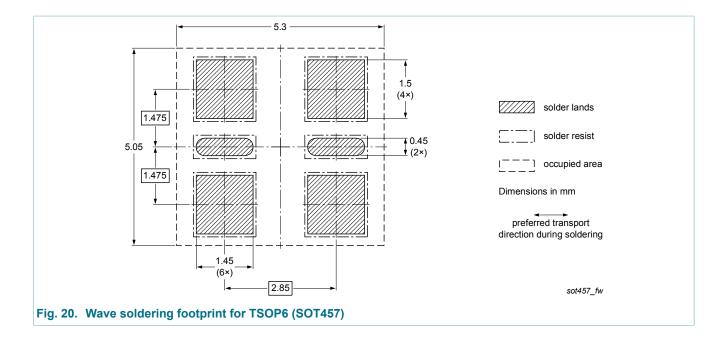


# 13. Soldering



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#### 20 V, P-channel Trench MOSFET



# 14. Revision history

| Table 8. Revision his | 8. Revision history |                    |               |            |  |  |  |
|-----------------------|---------------------|--------------------|---------------|------------|--|--|--|
| Data sheet ID         | Release date        | Data sheet status  | Change notice | Supersedes |  |  |  |
| PMN52XP v.1           | 20160129            | Product data sheet | -             | -          |  |  |  |

#### 20 V, P-channel Trench MOSFET

### 15. Legal information

#### 15.1 Data sheet status

| Document<br>status [1][2]            | Product<br>status [3] | Definition  |
|--------------------------------------|-----------------------|---|
| Objective<br>[short] data<br>sheet   | Development           | This document contains data from<br>the objective specification for product<br>development. |
| Preliminary<br>[short] data<br>sheet | Qualification         | This document contains data from the preliminary specification.                             |
| Product<br>[short] data<br>sheet     | Production            | This document contains the product specification.   |

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#### 20 V, P-channel Trench MOSFET

### 16. Contents

| 1    | General description1     |
|------|--------------------------|
| 2    | Features and benefits1   |
| 3    | Applications1            |
| 4    | Quick reference data 1   |
| 5    | Pinning information2     |
| 6    | Ordering information2    |
| 7    | Marking2                 |
| 8    | Limiting values3         |
| 9    | Thermal characteristics5 |
| 10   | Characteristics7         |
| 11   | Test information10       |
| 12   | Package outline 11       |
| 13   | Soldering11              |
| 14   | Revision history13       |
| 15   | Legal information14      |
| 15.1 | Data sheet status 14     |
| 15.2 | Definitions14            |
| 15.3 | Disclaimers14            |
| 15.4 | Trademarks 15            |

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